

Solvothermal Syntheses and Crystal Structures of New One-dimensional Selenogallates [bappH₂][Ga₂Se₄] (bapp = 1,4-Bis-(3-aminopropyl)piperazine) and [Mn(en)₃][Ga₂Se₅] (en = Ethylenediamine)

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Two new selenogallates, [bappH₂][Ga₂Se₄] (**1**) (bapp = 1,4-bis(3-aminopropyl)-piperazine) and [Mn(en)₃][Ga₂Se₅] (**2**) (en = ethylenediamine), have been synthesized under solvothermal conditions and structurally characterized by single-crystal X-ray diffraction. Compounds **1** and **2** contain one-dimensional polymeric chains {[Ga₂Se₄]²⁻}_∞ and {[Ga₂Se₅]²⁻}_∞, respectively. The negative charges of the polymeric chains are balanced by a protonated 1,4-bis(3-aminopropyl)piperazine cation in **1** and by the metal-amine complex cations [Mn(en)₃]²⁺ in **2**. TGA analyses have shown that compound **2** is thermally more stable than compound **1**.

Key words: Selenogallate, Organic Amine, Polyselenide, Solvothermal Synthesis, Crystal Structure

Introduction

Microporous materials have attracted a great deal of attention because of their applications in areas ranging from catalysis to molecular sieves and ion exchange [1]. To develop traditional applications of microporous materials, great efforts have been employed to expand oxide open frameworks to their chalcogenide analogs. Since Bedard first reported microporous sulfido compounds by replacing O²⁻ by S²⁻ in an oxide framework in 1989 [2], a number of microporous chalcogenide open frameworks containing elements of Group 13 (*e. g.* gallium and indium) have been synthesized and characterized [3–7]. These compounds have applications similar to zeolites because gallium and indium are in the same group as aluminum that is a key element in zeolite frameworks. In addition, they may find applications in catalysis and semiconductor technologies due to their novel properties as electrocatalysts, photocatalysts, semiconductors and fast ion conductors [8–12].

Solvothermal synthesis is the most efficient method for the preparation of metal chalcogeno (chalcogenido) frameworks of main group elements templated

by organo-ammonium or metal cations as counterions [13, 14]. Meanwhile, organic amines with different C/N ratios and molecular structures play a key role in the formation of various architectures. More recently, Feng and co-workers reported gallium and indium chalcogenide frameworks with protonated organic amines or alkali/alkaline earth metal cations (Li⁺, Na⁺, K⁺, Ca²⁺) [15, 16]. The structures of these materials are based on various building blocks of supertetrahedral (*T_n*) units, such as [InS₂]⁻, [Ga₄Se₈]⁴⁻, [Ga₁₀S₁₈]⁶⁻, and [M₄In₁₆S₃₃]¹⁰⁻ (*M* = Mn, Co, Zn, Cd), [Cu₅In₃₀S₅₄]¹³⁻, [Cu₇In₂₈S₅₃]¹⁵⁻ [17–22]. These building blocks are often organized to open frameworks by corner-sharing chalcogen elements. It is very interesting that [Ga₁₀S₁₆]²⁻ and [Ga₁₀S₁₈]⁶⁻ units may be organized by organic linkers such as dipyridine ligands to one- or two-dimensional inorganic-organic hybrid materials as reported by Vaqueiro *et al.* [23–25]. Dai and co-workers reported similar structures templated by metal-amine complexes of the type [M(L)_n]²⁺ (*M* = Mn, Fe, Co, Ni, Zn; L = ethylenediamine, 1,10-phenanthroline, 1,2-diaminopropane, diethylenetriamine, and 1,2-diaminocyclohexane; *n* = 2 ~ 3) [18, 26–30]. On

the other hand, chalcogen anions can be linked together to form polychalcogen anions under solvothermal conditions [31–34], such as chelating (Se–Se)^{2–} anions in the compound [Ga(en)₃][Ga₃Se₇(en)] (en = ethylenediamine) [35]. As an extension of our previous research of main group chalcogenometallates [36–39], we herein report on the solvothermal synthesis and structural characterization of a new polymeric selenogallate [bappH₂][Ga₂Se₄] (bapp = 1,4-bis(3-aminopropyl)piperazine) and a novel polyselenogallate anion [Ga₂Se₅]^{2–} templated by the metal-amine complex cation [Mn(en)₃]²⁺.

Experimental Section

Materials and measurements

1,4-Bis-(3-aminopropyl)piperazine (bapp) and ethylenediamine (en) were purchased from Alfa Aesar and used without further purification. All other reagents and solvents were used without further purification. Infrared spectra were recorded on a Nicolet 170sx FT-IR spectrophotometer with use of pressed KBr pellets. Elemental analyses were performed on a Perkin-Elmer 240C elemental analyzer. Thermogravimetric analysis was performed by using a Delta TGA instrument. The samples were heated under a nitrogen stream of 100 mL min^{–1} with a heating rate of 5 °C min^{–1}.

Preparation of [bappH₂][Ga₂Se₄] (1)

Gallium metal (69.7 mg, 1.0 mmol) and selenium powder (197 mg, 2.5 mmol) were mixed with 1,4-bis-(3-aminopropyl)piperazine (2.112 g, 16 mmol) and distilled water (2 mL) in a 23 mL Teflon-lined stainless-steel autoclave and stirred for 20 min. The vessel was sealed and heated to 170 °C for 6 d. Then the autoclave was cooled to r. t. Yellow prism-shaped crystals of [bappH₂][Ga₂Se₄] (**1**) were obtained and air dried. The yield based on Ga was *ca.* 46 %. – Elemental analysis for C₁₀H₂₆N₄Ga₂Se₄ (657.63): calcd. C 18.3, H 4.0, N 8.5; found C 18.2, H 3.9, N 8.5.

Preparation of [Mn(en)₃][Ga₂Se₅] (2)

Gallium metal (69.7 mg, 1.0 mmol), selenium powder (237.0 mg, 3.0 mmol) and Mn(CH₃COO)₂ · 4H₂O (147.0 mg, 0.6 mmol) were mixed with ethylenediamine (2.404 g, 40 mmol) and distilled water (2 mL) in a 23 mL Teflon-lined stainless-steel autoclave and stirred for 20 min. The vessel was sealed and heated to 190 °C for 6 d. Then the autoclave was cooled to r. t. Red bar-shaped crystals of [Mn(en)₃][Ga₂Se₅] (**2**) were obtained and air dried. The yield based on Ga was *ca.* 53 %. – Elemental analysis for C₆H₂₄N₆MnGa₂Se₅ (771.51): calcd. C 9.4, H 3.1, N 10.9; found C 9.3, H 3.1, N 10.8.

Table 1. Crystal data, data collection parameters and details of the structure refinement of compounds **1** and **2**.

Compound	1	2
Empirical formula	C ₁₀ H ₂₆ Ga ₂ N ₄ Se ₄	C ₆ H ₂₄ N ₆ MnGa ₂ Se ₅
Formula weight	657.63	771.51
Color, habit	yellow, prism	red, bar
Crystal size, mm ³	0.20 × 0.13 × 0.1	0.25 × 0.12 × 0.11
Crystal system	triclinic	orthorhombic
Space group	<i>P</i> $\bar{1}$	<i>Pbcn</i>
<i>a</i> , Å	6.3517(3)	9.7717(12)
<i>b</i> , Å	7.8498(4)	15.2971(19)
<i>c</i> , Å	10.7818(5)	13.7494(17)
α , deg	71.457(2)	90
β , deg	84.925(2)	90
γ , deg	72.084(3)	90
Volume, Å ³	484.93(4)	2055.2(4)
<i>Z</i>	1	4
Density (calcd.), g cm ^{–3}	2.30	2.50
Absorption coeff., mm ^{–1}	10.3	12.1
Temperature, K	296(2)	296(2)
<i>F</i> (000), e	312	1444
Radiation; λ , Å	MoK α ; 0.71073	MoK α ; 0.71073
Reflections collected	8593	11900
Unique reflections / <i>R</i> _{int}	2157 / 0.30	2339 / 0.037
Parameters refined	100	104
Final <i>R</i> 1 / <i>wR</i> 2	0.027 / 0.75	0.033 / 0.070
[<i>I</i> ≥ 2 σ (<i>I</i>)] ^{a,b}		
Final <i>R</i> 1 / <i>wR</i> 2 (all data) ^{a,b}	0.031 / 0.76	0.052 / 0.077
Weighting scheme A / B ^b	0.0290 / 0.0761	0.0700 / 0.
Goodness of fit (GoF) ^c	1.03	1.02
Final difference peaks, e Å ^{–3}	+0.75 / –0.86	+1.42 / –0.58

^a *R*1 = $\Sigma ||F_o| - |F_c|| / \Sigma |F_o|$; ^b *wR*2 = $[\Sigma w(F_o^2 - F_c^2)^2 / \Sigma w(F_o^2)^2]^{1/2}$, $w = [\sigma^2(F_o^2) + (AP)^2 + BP]^{-1}$, where $P = (\text{Max}(F_o^2, 0) + 2F_c^2) / 3$; ^c GoF = $[\Sigma w(F_o^2 - F_c^2)^2 / (n_{\text{obs}} - n_{\text{param}})]^{1/2}$.

X-Ray crystallography

Single crystals of compounds **1** and **2** were mounted in random orientation on glass fibers. Diffraction data were collected on a Bruker SMART Apex CCD diffractometer with MoK α radiation using an ω scan mode. The collected frames were processed with the software SAINT [40]. The dataset was corrected for absorption using the program SADABS [41]. Structures were solved by Direct Methods and refined by full-matrix least-squares on *F*² using the SHELXTL software package [42, 43]. All non-hydrogen atoms were refined anisotropically. The positions of all hydrogen atoms except the hydrogen atoms of the NH₂ groups were generated geometrically (C–H = 0.97 Å), assigned isotropic displacement parameters, and allowed to ride on their respective parent carbon atoms before the final cycle of least-squares refinement. Crystal data, data collection parameters and details of the structure refinement are given in Table 1.

CCDC 830581 and 830582 contain the supplementary crystallographic data for this paper. These data can be obtained free of charge from The Cambridge Crystallographic Data Centre via www.ccdc.cam.ac.uk/data_request/cif.

Results and Discussion

Solvothermal reaction of gallium metal with selenium powder 1,4-bis-(3-aminopropyl)piperazine and water in a molar ratio of 1:3:16:125 at 170 °C produced the new compound [bappH₂][Ga₂Se₄] (**1**). When the magnesium salt and ethylenediamine were employed in a similar reaction at 190 °C, a novel polyselenide compound [Mn(en)₃][Ga₂Se₅] (**2**) was obtained. However, no crystals were obtained in the absence of water. Selenium powder served as the source for the Se²⁻ anion by reaction between selenium and amine or OH⁻ under solvothermal conditions. Typically, the molar ratio of the chalcogen and the metal element employed should be more than 2.5 in similar reactions. The IR absorption bands with variable intensities in the frequency range of 2910–3150 cm⁻¹ for ν(NH₃) indicate the presence of the protonated amine in compound **1** while the strong bands in the range of 3220–3440 cm⁻¹ in the IR spectrum of compound **2** correspond to the stretching vibrations of NH₂ from ethylenediamine [44].

X-Ray structural analyses revealed that compound **1** crystallizes in the triclinic space group *P* $\bar{1}$ and consists of one-dimensional polymeric gallium selenide {[Ga₂Se₅]²⁻}_∞ anions and protonated 1,4-bis-(3-aminopropyl)piperazine cations. The chain can be described as GaSe₄ tetrahedra sharing opposite edges. The Ga atom is coordinated to four Se atoms with an average bond length of 2.4158(4) Å, forming a slightly distorted tetrahedron with bond angles Se-Ga-Se ranging from 96.543(15) to 120.446(18)° (Figs. 1 and 2). The bond lengths and angles in **1** are similar to those found in a similar compound [Co(en)₃][Ga₂Se₄] [28]. Two terminal NH₂ groups in 1,4-bis-(3-aminopropyl)piperazine were protonated and function as charge-compensating cations and templates for the direct for-

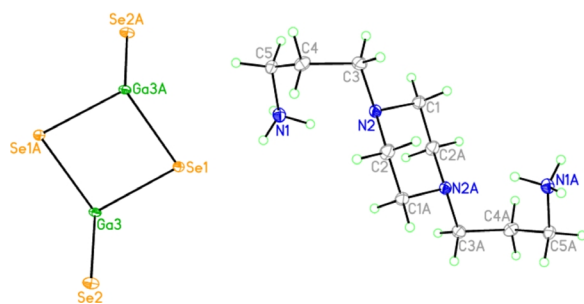


Fig. 1. The structure of **1** with atom labeling and displacement ellipsoids drawn at the 40 % probability level.

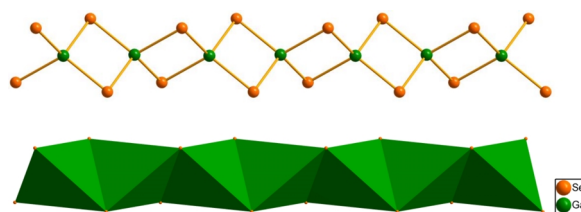


Fig. 2. View of the chain built by tetrahedral GaSe₄ units sharing opposite edges (top) and its polyhedral connection (bottom) in complex **1** as shown along the crystallographic *b* axis.

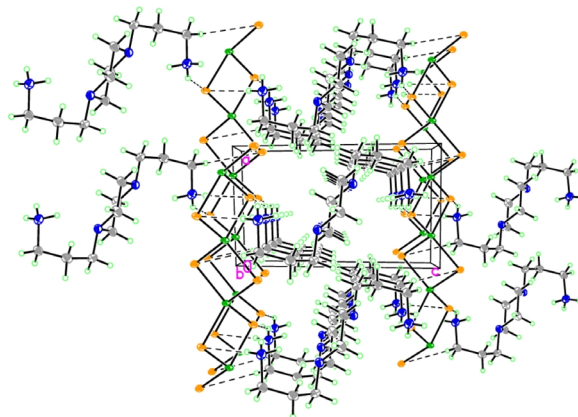


Fig. 3. View of the three-dimensional arrangement of the anions and cations in **1** (view along the *b* axis) as resulting from weak N-H...Se hydrogen bonds.

mation of the framework. The average distance between two adjacent gallium atoms is 3.177(1) Å. In addition, the polymeric anions and the protonated amine cations are organized to an extended three-dimensional network by weak N-H...Se hydrogen bonds between terminal nitrogen atoms of the bapp ligands and selenium atoms of the polymeric anions, with the distances varying from 3.405(4) to 3.477(4) Å. The cations occupy the space between polymeric anions, as shown in Fig. 3.

Compound **2** crystallizes in the orthorhombic space group *Pbcn* with four formula units in the unit cell. It consists of a polymeric gallium polyselenide chain of {[Ga₂Se₅]²⁻}_∞ with the metal-amine complex [Mn(en)₃]²⁺ as charge-compensating cations. The {[Ga₂Se₅]²⁻}_∞ chain can be described as tetrahedral GaSe₄ units sharing three edges and chelating another edge to form alternating four-membered rings Ga₂Se₂ and five-membered rings Ga₂Se₃ (Figs. 4 and 5). The bond length of chelating Se-Se is 2.3334(10) Å. The Ga³⁺ ion is coordinated to four Se atoms with an average bond length of 2.4056(7) Å, forming

- [1] M. E. Davis, *Nature* **2002**, 417, 813.
- [2] R. L. Bedard, S. T. Wilson, L. D. Vail, J. M. Bennett, E. M. Flanigen in *Zeolites: Facts, Figures, Future*. Proceedings of the 8th International Zeolite Conference, (Eds.: P. A. Jacobs, R. A. Santen), Elsevier, Amsterdam, **1989**, p. 375.
- [3] Y. Dong, Q. Peng, R. Wang, Y. Li, *Inorg. Chem.* **2003**, 42, 1794.
- [4] C. L. Cahill, B. Gugliotta, J. B. Parise, *Chem. Commun.* **1998**, 1715.
- [5] C. L. Cahill, J. B. Parise, *J. Chem. Soc., Dalton Trans.* **2000**, 1475.
- [6] P. Vaqueiro, *Inorg. Chem.* **2006**, 45, 4150.
- [7] H. Li, J. Kim, M. O'Keeffe, O. M. Yaghi, *Angew. Chem.* **2003**, 115, 1817; *Angew. Chem. Int. Ed.* **2003**, 42, 1819.
- [8] N. Zheng, X. Bu, H. Vu, P. Feng, *Angew. Chem.* **2005**, 117, 5433; *Angew. Chem. Int. Ed.* **2005**, 44, 5299.
- [9] X. Bu, N. Zheng, X. Wang, B. Wang, P. Feng, *Angew. Chem.* **2004**, 116, 1528; *Angew. Chem. Int. Ed.* **2004**, 43, 1502.
- [10] N. Zheng, X. Bu, P. Feng, *Angew. Chem.* **2004**, 116, 4857; *Angew. Chem. Int. Ed.* **2004**, 43, 4753.
- [11] N. Zheng, X. Bu, P. Feng, *Nature* **2003**, 426, 428.
- [12] N. Zheng, X. Bu, P. Feng, *J. Am. Chem. Soc.* **2005**, 127, 5286.
- [13] B. Seidlhofer, N. Pienack, W. Bensch, *Z. Naturforsch.* **2010**, 65b, 937.
- [14] A. Kromm, T. van Almsick, W. S. Sheldrick, *Z. Naturforsch.* **2010**, 65b, 918.
- [15] N. Zheng, X. Bu, B. Wang, P. Feng, *Science* **2002**, 298, 2366.
- [16] C. Wang, X. Bu, N. Zheng, P. Feng, *Chem. Commun.* **2002**, 1344.
- [17] P. Vaqueiro, *J. Solid State Chem.* **2006**, 179, 302.
- [18] J. Zhou, Y. Zhang, G.-Q. Bian, C.-Y. Li, X.-X. Chen, J. Dai, *Cryst Growth Des* **2008**, 8, 2235.
- [19] N. Zheng, X. Bu, P. Feng, *J. Am. Chem. Soc.* **2003**, 125, 1138.
- [20] C. Wang, Y. Li, X. Bu, N. Zheng, O. Zivkovic, C.-S. Yang, P. Feng, *J. Am. Chem. Soc.* **2001**, 123, 11506.
- [21] X. Bu, N. Zheng, Y. Li, P. Feng, *J. Am. Chem. Soc.* **2002**, 124, 12646.
- [22] L. Wang, T. Wu, F. Zuo, X. Zhao, X. Bu, J. Wu, P. Feng, *J. Am. Chem. Soc.* **2010**, 132, 3283.
- [23] P. Vaqueiro, M. L. Romero, *J. Am. Chem. Soc.* **2008**, 130, 9630.
- [24] P. Vaqueiro, M. L. Romero, *Inorg. Chem.* **2009**, 48, 810.
- [25] P. Vaqueiro, M. L. Romero, B. C. Rowan, B. S. Richards, *Chem Eur J* **2010**, 16, 4462.
- [26] J. Zhou, Y. Zhang, G.-Q. Bian, Q.-Y. Zhu, C.-Y. Li, J. Dai, *Cryst Growth Des* **2007**, 7, 1889.
- [27] J. Zhou, G.-Q. Bian, Y. Zhang, Q.-Y. Zhu, C.-Y. Li, J. Dai, *Inorg. Chem.* **2007**, 46, 6347.
- [28] Z.-X. Lei, Q.-Y. Zhou, X. Zhang, W. Luo, W.-Q. Mu, J. Dai, *Inorg. Chem.* **2010**, 49, 4385.
- [29] Y.-H. Wang, M.-H. Zhang, Y.-M. Yan, G.-Q. Bian, Q.-Y. Zhu, J. Dai, *Inorg. Chem.* **2010**, 49, 9731.
- [30] J. Zhou, C.-Y. Li, Y. Zhang, J. Dai, *J. Coord. Chem.* **2009**, 62, 1112.
- [31] W. Bensch, M. Schur, *Z. Kristallogr.* **1997**, 212, 305.
- [32] M. Schur, W. Bensch, *Z. Anorg. Allg. Chem.* **1998** 624, 310.
- [33] H. Rijnberk, C. Näther, M. Schur, I. Jeß, *Acta Crystallogr.* **1998**, C54, 920.
- [34] F. Wendland, C. Näther, W. Bensch, *Z. Naturforsch.* **2004**, 59b, 629.
- [35] A. Fehler, R. Blachnik, H. Reuter, *Z. Anorg. Allg. Chem.* **1999**, 625, 1225.
- [36] Y.-G. Han, C. Xu, T. Duan, Q.-F. Zhang, W.-H. Leung, *J. Mol. Struct.* **2009**, 936, 15.
- [37] Y.-G. Han, C. Xu, T. Duan, Q.-F. Zhang, *Inorg. Chim. Acta* **2011**, 365, 414.
- [38] Y.-G. Han, C. Xu, T. Duan, F.-H. Wu, Q.-F. Zhang, W.-H. Leung, *Inorg. Chem.* **2009**, 48, 8796.
- [39] C. Xu, J.-J. Zhang, T. Duan, Q. Chen, Q.-F. Zhang, *J. Cluster Sci.* **2010**, 21, 813.
- [40] SMART and SAINT+ for Windows NT (version 6.02a), Bruker Analytical X-ray Instruments Inc., Madison, Wisconsin (USA) **1998**.
- [41] G. M. Sheldrick, SADABS, Program for Empirical Absorption Correction of Area Detector Data, University of Göttingen, Göttingen (Germany) **1996**.
- [42] G. M. Sheldrick, SHELXTL (version 5.1), Software Reference Manual, Bruker Analytical X-ray Instruments Inc., Madison, Wisconsin (USA) **1997**.
- [43] G. M. Sheldrick, *Acta Crystallogr.* **2008**, A64, 112.
- [44] S. Dehnen, C. Zimmermann, *Z. Anorg. Allg. Chem.* **2002**, 628, 2463.